

PMLL4148L; **PMLL4448**

High-speed switching diodes Rev. 07 — 31 January 2007

Product data sheet

Product profile

1.1 General description

Single high-speed switching diodes, fabricated in planar technology, and encapsulated in small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) packages.

Table 1. **Product overview**

Type number	Package	Configuration
PMLL4148L	SOD80C	single
PMLL4448		

1.2 Features

High switching speed: t_{rr} ≤ 4 ns

Reverse voltage: V_R ≤ 75 V

Repetitive peak reverse voltage: V_{RRM} ≤ 100 V

Repetitive peak forward current: I_{FRM} ≤ 450 mA

Small hermetically sealed glass SMD package

1.3 Applications

- High-speed switching
- Reverse polarity protection

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		[1] -	-	200	mA
I _{FRM}	repetitive peak forward current		-	-	450	mA
V_R	reverse voltage		-	-	75	V



Table 2. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage					
	PMLL4148L	$I_F = 50 \text{ mA}$	-	-	1	V
	PMLL4448	$I_F = 5 \text{ mA}$	620	-	720	mV
		$I_F = 100 \text{ mA}$	-	-	1	V
t _{rr}	reverse recovery time		[2] _	-	4	ns

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footbrint.

2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	
2	anode	k	+
			sym006

^[1] The marking band indicates the cathode.

3. Ordering information

Table 4. Ordering information

Type number	Package				
	Name	Description	Version		
PMLL4148L	-	9.,	SOD80C		
PMLL4448		2 connectors			

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PMLL4148L	marking band
PMLL4448	marking band

^[1] black: made in Philippines brown: made in China

^[2] When switched from I_F = 10 mA to I_R = 60 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• •	•		
Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	75	V
I _F	forward current		<u>[1]</u> _	200	mA
I _{FRM}	repetitive peak forward current		-	450	mA
I _{FSM}	non-repetitive peak forward	square wave	[2]		
	current	t _p = 1 μs	-	4	Α
		$t_p = 1 \text{ ms}$	-	1	Α
		t _p = 1 s	-	0.5	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1] _	500	mW
Tj	junction temperature		-	200	°C
T _{amb}	ambient temperature		-65	+200	°C
T _{stg}	storage temperature		-65	+200	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	350	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	300	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] $T_i = 25$ °C prior to surge.

7. Characteristics

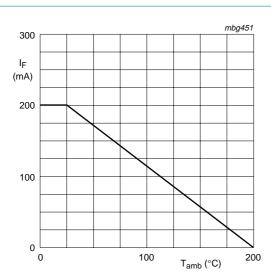
Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage					
	PMLL4148L	$I_F = 50 \text{ mA}$	-	-	1	V
	PMLL4448	$I_F = 5 \text{ mA}$	620	-	720	mV
		$I_F = 100 \text{ mA}$	-	-	1	V
I _R	reverse current	V _R = 20 V	-	-	25	nA
		$V_R = 20 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I _R	reverse current					
	PMLL4448	$V_R = 20 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	-	3	μΑ
C _d	diode capacitance	$V_R = 0 V$; $f = 1 MHz$	-	-	4	pF
t _{rr}	reverse recovery time		<u>[1]</u> -	-	4	ns
V_{FR}	forward recovery voltage)	[2] _	-	2.5	V

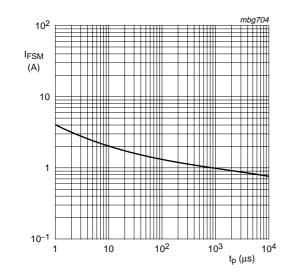
^[1] When switched from I_F = 10 mA to I_R = 60 mA; R_L = 100 $\Omega;$ measured at I_R = 1 mA.

^[2] When switched from I_F = 50 mA; t_r = 20 ns.



FR4 PCB, standard footprint

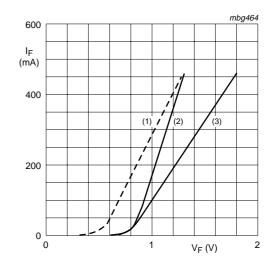
Fig 1. Forward current as a function of ambient temperature; derating curve



Based on square wave currents.

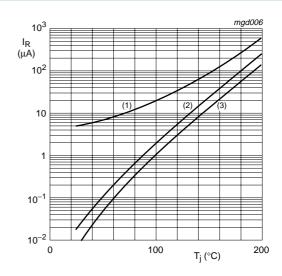
 $T_i = 25$ °C; prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values



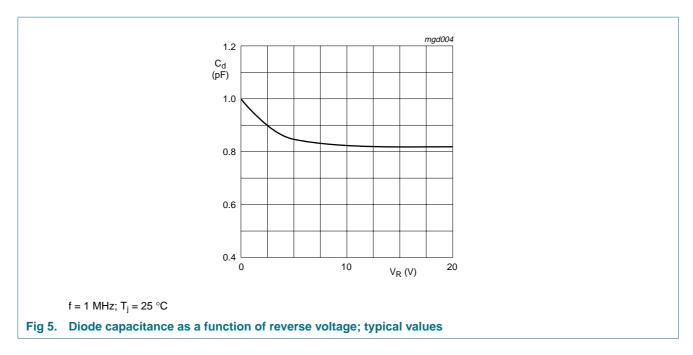
- (1) $T_i = 175 \,^{\circ}C$; typical values
- (2) $T_i = 25$ °C; typical values
- (3) $T_i = 25 \,^{\circ}C$; maximum values

Fig 2. Forward current as a function of forward voltage

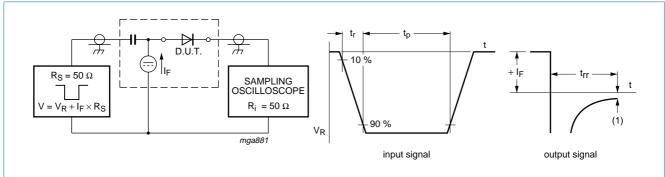


- (1) $V_R = 75 \text{ V}$; maximum values
- (2) $V_R = 75 \text{ V}$; typical values
- (3) $V_R = 20 \text{ V}$; typical values

Fig 4. Reverse current as a function of junction temperature

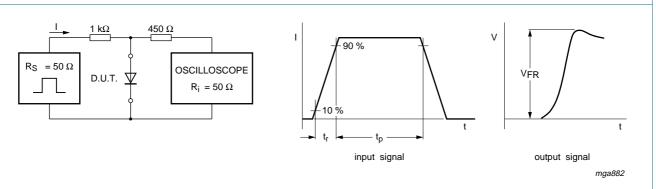


8. Test information



(1) $I_R = 1$ mA Input signal: reverse pulse rise time $t_r = 0.6$ ns; reverse voltage pulse duration $t_p = 100$ ns; duty cycle $\delta \le 0.05$ Oscilloscope: rise time $t_r = 0.35$ ns

Fig 6. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

Fig 7. Forward recovery voltage test circuit and waveforms

PMLL4148L_PMLL4448_7 © NXP B.V. 2007. All rights reserved.

9. Package outline

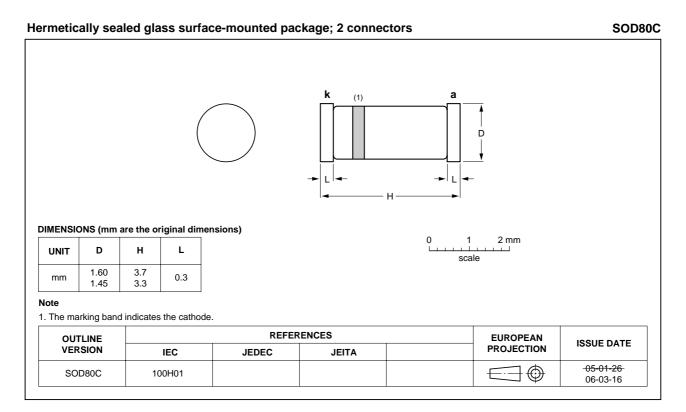


Fig 8. Package outline SOD80C

10. Packing information

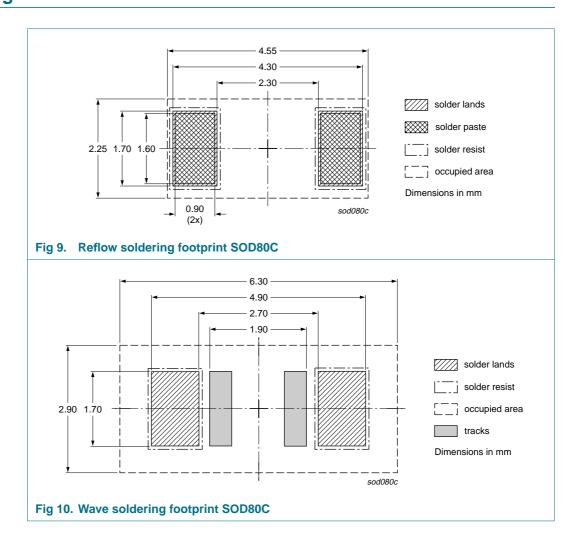
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	nber Package Description		Packing quantity		
			2500	10000	
PMLL4148L	SOD80C	4 mm pitch, 8 mm tape and reel	-115	-135	
PMLL4448					

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
PMLL4148L_PMLL4448_7	20070131	Product data sheet	-	PMLL4148L_PMLL4448_6	
Modifications:		of this data sheet has beer of NXP Semiconductors.	redesigned to com	ply with the new identity	
	 Legal texts 	have been adapted to the r	new company name	where appropriate.	
	• Section 1.2	"Features": adapted			
 Section 1.3 "Applications": amended 					
	 <u>Table 2 "Quick reference data"</u>: V_F conditions for PMLL4148L updated 				
	 <u>Table 8 "Characteristics"</u>: V_F conditions for PMLL4148L updated 				
	• Figure 4: un	nit for I _R in axis description	amended to μA		
	 Section 13 ' 	'Legal information": update	d		
PMLL4148L_PMLL4448_6	20050404	Product data sheet	-	PMLL4148L_4448_5	
PMLL4148L_4448_5	20020123	Product specification	-	PMLL4148L_4448_4	
PMLL4148L_4448_4	20001115	Product specification	-	PMLL4148_3	
PMLL4148_3	19990527	Product specification	-	PMLL4148_2	
PMLL4148_2	19960918	Product specification	-	PMLL4148_1	
PMLL4148_1	19960423	Product specification	-	-	

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

13.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For additional information, please visit: http://www.nxp.com

For sales office addresses, send an email to: salesaddresses@nxp.com

15. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information
4	Marking 2
5	Limiting values
6	Thermal characteristics 3
7	Characteristics 4
8	Test information 6
9	Package outline
10	Packing information 7
11	Soldering 8
12	Revision history 9
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks 10
14	Contact information
15	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

